

ROITHNER LASERTECHNIK GIRDH

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LED19-SMD5

TECHNICAL DATA



Mid-Infrared Light Emitting Diode, SMD

Light Emitting Diodes with central wavelength 1.95 µm series are based on heterostructures grown on GaSb substrates. Solid solutions GaInAsSb are used in active layer. Wide band gap solid solutions AlGaAsSb with Al content 64% are used for good electron confinement. LED19-SMD5 has a stable ouput power and a lifetime more then 80000 hours.

Features

Structure: GalnAsSb/AlGaAsSb
Peak Wavelength: typ. 1.95 µm

Optical Ouput Power: typ. 1.0 mW qCW

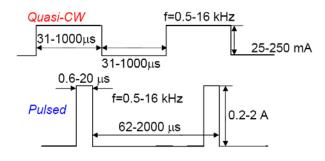
Package: SMD 5x5 mm



Specifications

ltem	Condition		Rating		Unit
item	Condition	Min.	Тур.	Max.	
Peak Wavelength	T=300 K	1.92	1.95	1.97	μm
FWHM	150 mA CW	100	150	200	nm
Quasi-CW Optical Power	200 mA qCW	0.8	1.0	1.2	mW
Pulsed Optical Power	1 A	22	25	30	mW
Switching Time	T=300 K	10	20	30	ns
Operation Voltage	200 mA qCW				V
Operating Temperature		-240 +	50		°C
Emitting Area		300x300)		μm
Soldering Temperature		180			°C
Package	SMD type p therm	ackage 5) al conduc			igh

Operating Regime



Quasi-CW

- Maximum current 220 mA
- Recommended current 150-200mA

Pulsed

 Maximum current 1 A (puls lenght 500 ns, repetition rate 2kHz)



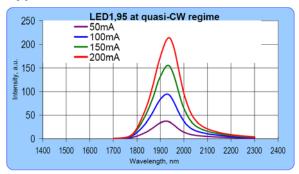
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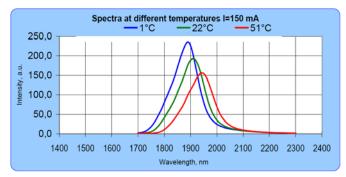
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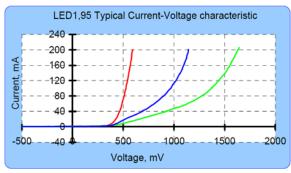
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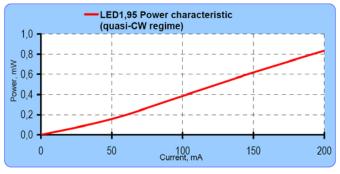


Typical Performance Curves

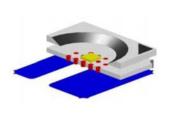


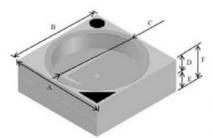






Package





ITEM	Symbol	Rule	
Basic Outline	A	5.0± 0.1mm	
Basic Outline	В	5.0± 0.1mm	
Cavity size	С	Max 4.2Φ	
Top layer	D	Min 0.4mm	
Bottom layer	E	Min 0.4mm	
Thickness	F	Max 2mm	

- · Tiny package for surface mounting
- Anode and cathode are led to the metalized areas on the back side of the ceramic surface
- Material Low Temperature Co-fired Ceramic (LTCC):
 - thermal conductivity 25 W/mK
 - thermoresistance 8 °C/W